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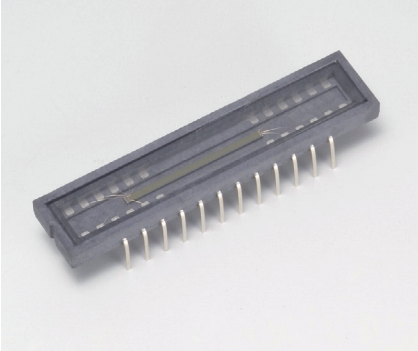
CMOS linear image sensor



S10077

Digital output, built-in 8/10-bit A/D converter, single power supply operation

The S10077 is a CMOS linear image sensor designed for image input applications. The signal processing circuit has a charge amplifier with excellent input/output characteristics. The circuit also includes a 8-bit/10-bit A/D converter.

Features

- **Pixel pitch: 14 µm**
  Pixel height: 50 µm
- **1024 pixels**
- **Single power supply operation: 3.3 to 5 V**
- **On-chip charge amplifier with excellent input/output characteristics**
- **Built-in timing generator allows operation with only start and clock pulse inputs.**
- **Video data rate: 1 MHz max.**
- **Spectral response range: 400 to 1000 nm**
- **Digital output**
- **8-bit/10-bit switchable ADC**
- **Simultaneous all-pixel integration and variable integration time function**
- **Low power consumption**

Applications

- **Analytical instruments**
- **Position detection**
- **Image reading**

Structure

Parameter	Specification	Unit
Number of pixels	1024	-
Pixel pitch	14	µm
Pixel height	50	µm
Photosensitive area length	14.336	mm
Package	LCP (liquid crystal polymer)	-
Window material	Borosilicate glass	-

Absolute maximum ratings

Parameter	Symbol	Condition	Value	Unit
Supply voltage	Vdd	Ta=25 °C	-0.3 to +6	V
A/D mode selection voltage	Vsel	Ta=25 °C	-0.3 to +6	V
Clock pulse voltage	V(CLK)	Ta=25 °C	-0.3 to +6	V
Start pulse voltage	V(ST)	Ta=25 °C	-0.3 to +6	V
Operating temperature*1	Topr		-5 to +50	°C
Storage temperature*1	Tstg		-10 to +60	°C

*1: No condensation

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Recommended terminal voltage

Parameter		Symbol	Min.	Typ.	Max.	Unit
Supply voltage		Vdd	3.3	5	5.25	V
AD mode selection voltage	8-bit	Vsel	0	-	0.4	V
	10-bit		Vdd - 0.25	Vdd	Vdd + 0.25	V
Clock pulse voltage	High level	V(CLK)	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level		0	-	0.4	V
Start pulse voltage	High level	V(ST)	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level		0	-	0.4	V

Electrical characteristics (Ta=25 °C)

Parameter			Symbol	Min.	Typ.	Max.	Unit
Clock pulse frequency		8-bit	f(CLK)	1 M	-	12 M	Hz
		10-bit		1 M	-	6 M	
Data rate			DR	-	f(CLK)/12	-	Hz
Digital output rise time (10 to 90%)		CL=10 pF*2	tr	-	-	30	ns
		CL=30 pF*2		-	-	60	
Digital output fall time (90 to 10%)		CL=10 pF*2	tf	-	-	30	ns
		CL=30 pF*2		-	-	60	
Current consumoption	Vdd=3.3 V	8-bit*3	Ic	-	12	-	mA
		10-bit*4		-	10	-	
	Vdd=5 V	8-bit*3		-	16	-	
		10-bit*4		-	14	-	

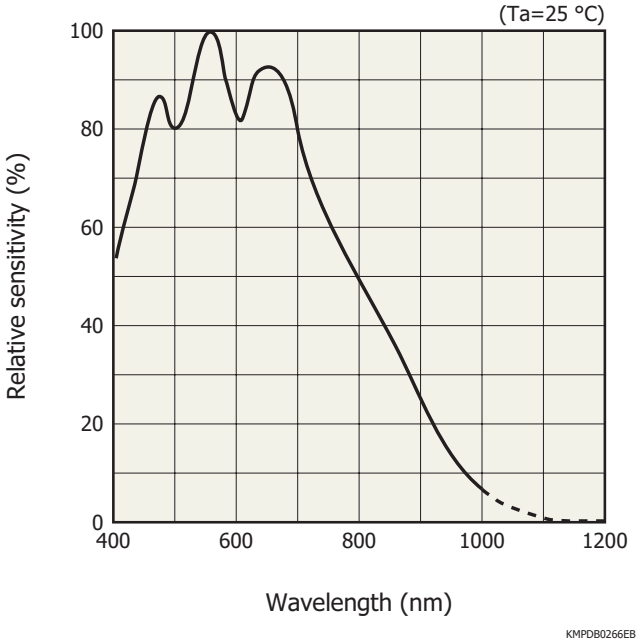
*2: CL=Load capacitance of digital output terminal
*3: f(CLK)=12 MHz
*4: f(CLK)=6 MHz

Electrical and optical characteristics (Ta=25 °C)

Parameter			Symbol	Min.	Typ.	Max.	Unit
Spectral response range			λ		400 to 1000		nm
Peak sensitivity wavelength			λp	-	700	-	nm
Photosensitivity*5			R	-	30	-	V/lx · s
Dark output*6	Vdd=3.3 V	8-bit*7	Dd	-	0.04	0.6	digit
		10-bit*8		-	0.16	2.4	
	Vdd=5 V	8-bit*7		-	0.03	0.6	
		10-bit*8		-	0.12	2.4	
Saturation output*9	Vdd=3.3 V	8-bit*7	Dsat	255	-	-	digit
		10-bit*8		1023	-	-	
	Vdd=5 V	8-bit*7		255	-	-	
		10-bit*8		1023	-	-	
Readout noise	Vdd=3.3 V	8-bit*7	Nread	-	0.7	2	digit
		10-bit*8		-	2.8	8	
	Vdd=5 V	8-bit*7		-	0.7	2	
		10-bit*8		-	2.8	8	
Offset output	Vdd=3.3 V	8-bit*7	Doffset	11	29	41	digit
		10-bit*8		44	116	164	
	Vdd=5 V	8-bit*7		7	19	27	
		10-bit*8		28	76	108	
Photoresponse nonuniformity*5 *10			PRNU	-	-	±10	%

*5: Measured with a tungsten lamp of 2856 K
*6: Integration time Ts=10 s
*7: f(CLK)=12 MHz
*8: f(CLK)=6 MHz
*9: Absolute value with respect to 0 digit
*10: Photoresponse nonuniformity (PRNU) is the output nonuniformity that occurs when the entire photosensitive area is uniformly illuminated by light which is 50% of the saturation exposure level. PRNU is measured using 1022 pixels excluding the pixels at both ends, and is defined as follows:
PRNU= ΔX/X × 100 (%)
X: average output of all pixels, ΔX: difference between X and maximum or minimum output

Spectral response (typical example)

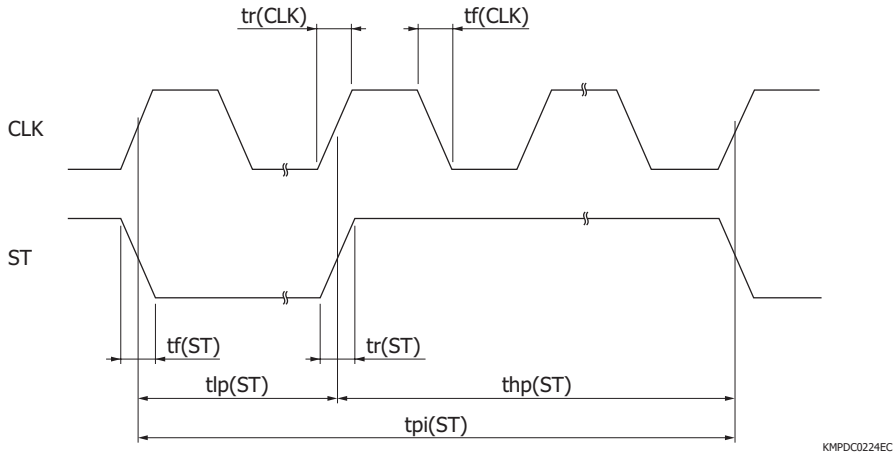


A/D converter specifications (Ta=25 °C)

Parameter		Symbol	Specification	Unit
Digital output format		-	Serial output	-
Resolution*11	8-bit mode	RESO	8	bit
	10-bit mode		10	
Conversion voltage range*12	Vdd=3.3 V	-	0 to 2.2	V
	Vdd=5 V		0 to 3.3	

*11: Vsel=0 V (8-bit mode), Vdd (10-bit mode)
*12: Digital output is available from MSB as serial output.
8-bit mode: D7 to D0
10-bit mode: D9 to D0

Timing Chart

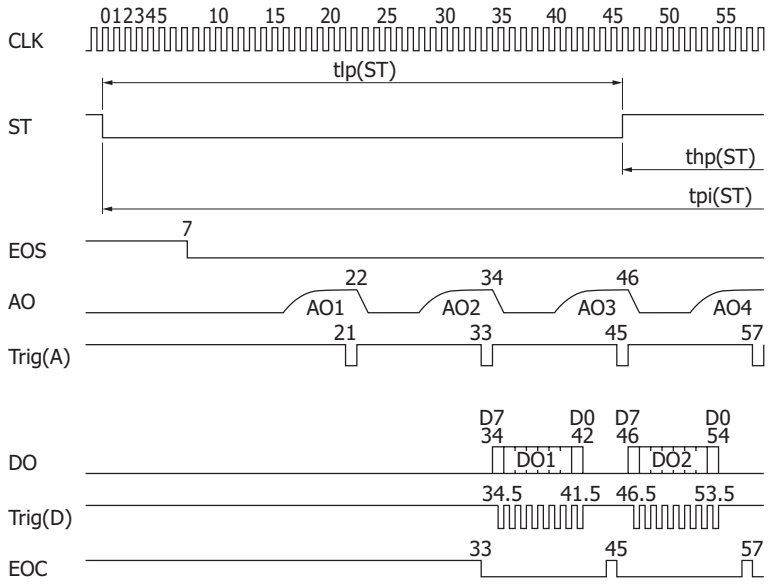


Parameter	Symbol	Min.	Typ.	Max.	Unit
Start pulse interval	tpi(ST)	12339/f(CLK)	-	120000/f(CLK)	s
Start pulse low period	tlp(ST)	45/f(CLK)	-	-	s
Start pulse high period*13	thp(ST)	6000/f(CLK)	-	-	s
Start pulse rise and fall times	tr(ST), tf(ST)	0	20	30	ns
Clock pulse duty	-	40	50	60	%
Clock pulse rise and fall times	tr(CLK), tf(CLK)	0	20	30	ns

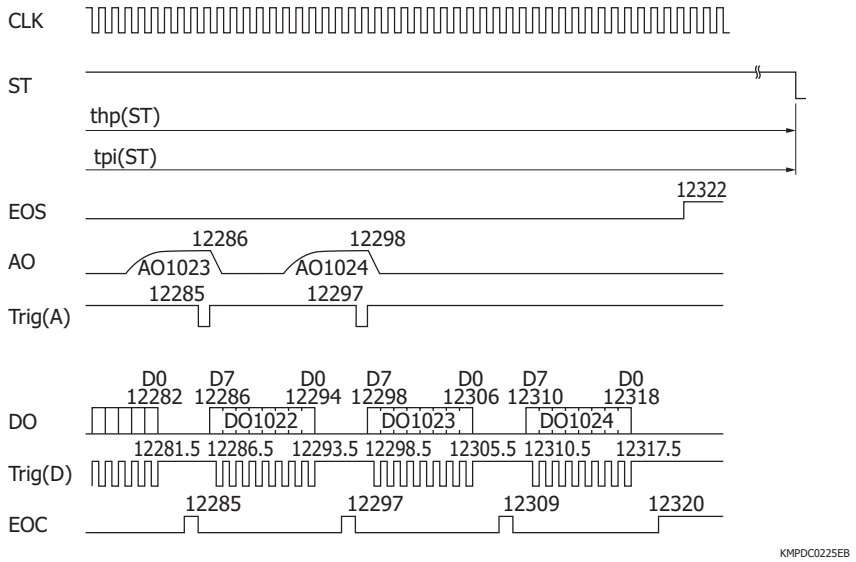
*13: Signal charge integration time equals the high period of start pulse + 7 CLK cycles.
The shift register operation starts at the fall of CLK pulse immediately after ST pulse sets to low.
Integration time can be changed by changing the high-to-low ratio of ST pulses.

8-bit mode

■ In the neighborhood of start pixel



■ In the neighborhood of last pixel



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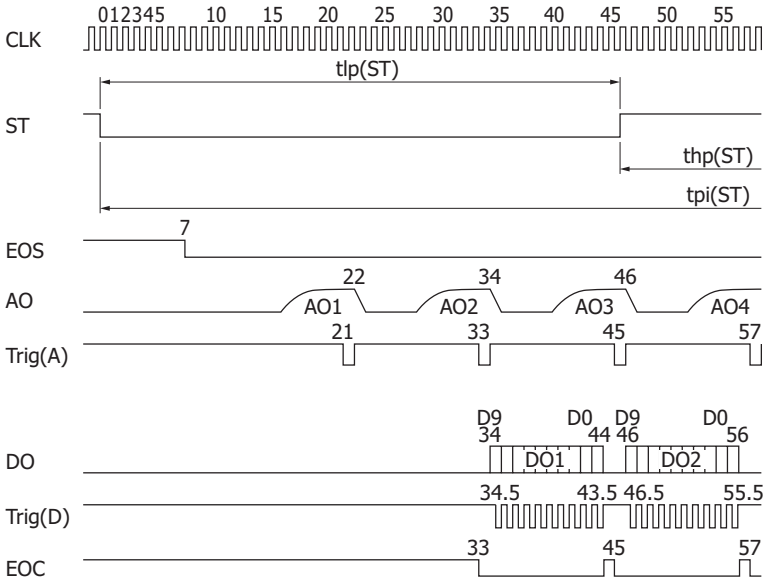
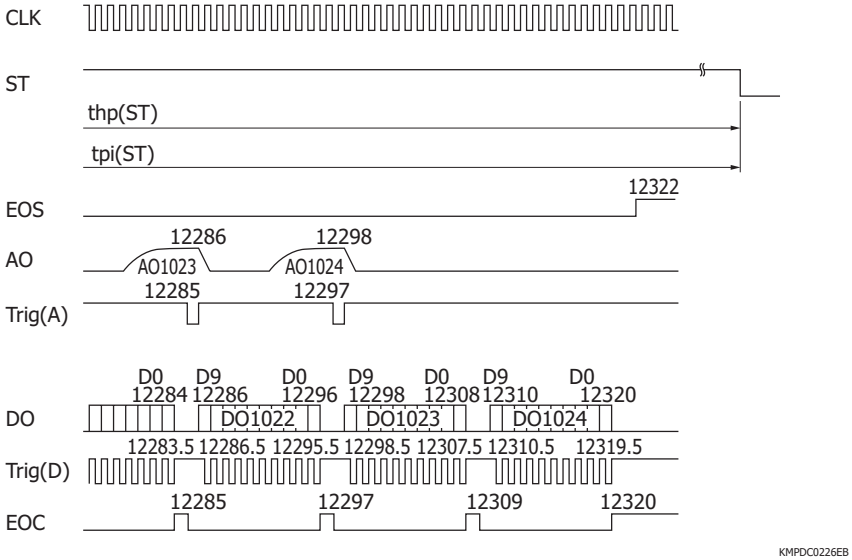
Note: When using analog output AO, read the AO output at the falling edge of Trig(A).
When using digital output DO, read the DO output at the falling edge of Trig(D).

10-bit mode

■ In the neighborhood of start pixel



■ In the neighborhood of last pixel



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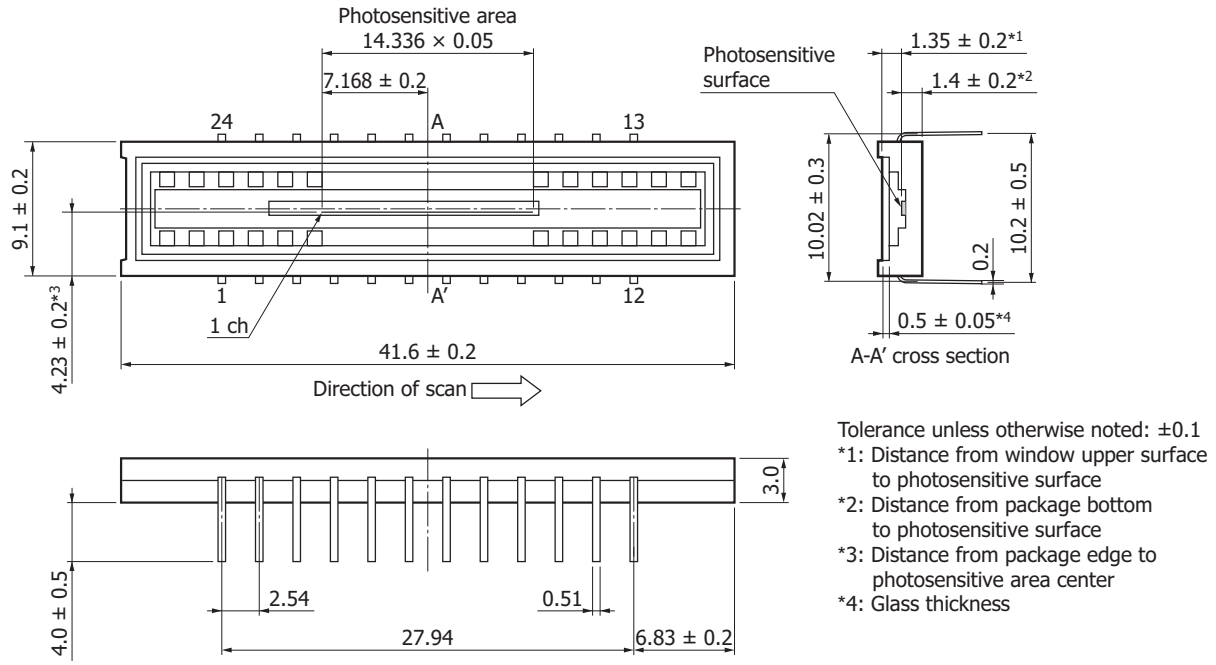
Note: When using analog output AO, read the AO output at the falling edge of Trig(A).
When using digital output DO, read the DO output at the falling edge of Trig(D).

Dimensional outline (unit: mm)



Tolerance unless otherwise noted: ±0.1
*1: Distance from window upper surface to photosensitive surface
*2: Distance from package bottom to photosensitive surface
*3: Distance from package edge to photosensitive area center
*4: Glass thickness

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Pin connections

Pin no.	Symbol	I/O	Discription	Pin no.	Symbol	I/O	Discription
1	NC		No connection	13	NC		No connection
2	D.Trig	O	Trigger signal for digital output	14	NC		No connection
3	DO	O	Digital output	15	NC		No connection
4	A.Trig	O	Trigger signal for analog output	16	EOS	O	End of scan signal
5	AO	O	Analog output	17	EOC	O	Digital conversion end signal
6	NC		No connection	18	NC		No connection
7	NC		No connection	19	Vsel	I	A/D mode selection voltage
8	Vdd	I	Supply voltage	20	Vss	I	GND
9	Vss	I	GND	21	Vdd	I	Supply voltage
10	NC		No connection	22	CLK	I	Clock signal
11	NC		No connection	23	ST	I	Start signal
12	NC		No connection	24	NC		No connection

Note: Leave the "NC" terminals open and do not connect them to GND.
When using the analog output terminal, connect a buffer amplifier for impedance conversion to it so as to minimize the current flow. As the buffer amplifier, use a high input impedance operational amplifier with JFET or CMOS input.

Precautions

(1) Electrostatic countermeasures

This device has a built-in protection circuit against static electrical charges. However, to prevent destroying the device with electrostatic charges, take countermeasures such as grounding yourself, the workbench and tools to prevent static discharges. Also protect this device from surge voltages which might be caused by peripheral equipment.

(2) Incident window

If dust or dirt gets on the light incident window, it will show up as black blemishes on the image. When cleaning, avoid rubbing the window surface with dry cloth or dry cotton swab, since doing so may generate static electricity. Use soft cloth, paper or a cotton swab moistened with alcohol to wipe dust and dirt off the window surface. Then blow compressed air onto the window surface so that no spot or stain remains.

(3) Soldering

To prevent damaging the device during soldering, take precautions to prevent excessive soldering temperatures and times. Soldering should be performed within 5 seconds at a soldering temperature below 260 °C.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

· Disclamer

· Image sensors/Precautions

Information described in this material is current as of May 2019.
Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.
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